

1.Features

- $V_{DS}=30V$
- $I_D=86A$
- $R_{DS(ON)}<6.5m\Omega(V_{GS}=10V)$

3.Applications

- High Frequency Synchronous Buck Converters for Computer Processor Power
- Lead-Free

2.Benefits

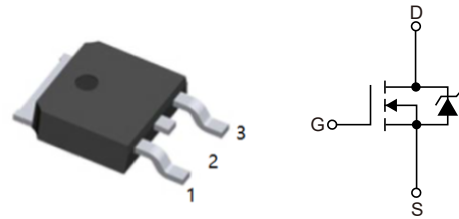
- Very Low $R_{DS(ON)}$ at 4.5V V_{GS}
- Ultra-Low Gate Impedance
- Fully Characterized Avalanche Voltage and Current

- High Frequency Isolated DC-DC Converters with Synchronous Rectification for Telecom and Industrial Use

4.Pinning information

Pin	Symbol	Description
1	G	GATE
3	S	SOURCE
2	D	DRAIN

TO-252(DPAK)
top view



5.Absolute Maximum Ratings

Parameter		Symbol	Rating	Units
Drain- Source Voltage		V_{DS}	30	V
Gate-to-Source Voltage		V_{GS}	± 20	V
Continuous Drain Current, $V_{GS}=10V$	$T_C=25^\circ C$	I_D	86 ④	A
Continuous Drain Current, $V_{GS}=10V$	$T_C=100^\circ C$		61 ④	A
Pulsed Drain Current ①		I_{DM}	340	A
Maximum Power Dissipation	$T_C=25^\circ C$	P_D	79	W
Maximum Power Dissipation	$T_C=100^\circ C$		39	W
Linear Derating Factor			0.53	W/°C
Operating Junction and Storage Temperature Range		T_J	-55 to 175	°C
Soldering Temperature, for 10 seconds (1.6mm from case)		T_{STG}	300	°C



6. Thermal resistance rating

Parameter	Symbol	Typ	Max	Units
Junction-to-Case	$R_{\theta JC}$		1.9	°C/W
Junction-to-Ambient (PCB Mount) ⑤	$R_{\theta JA}$		50	°C/W
Junction-to-Ambient	$R_{\theta JA}$		110	°C/W



7. Electrical Characteristics @ $T_J = 25^\circ\text{C}$ (unless otherwise specified)

Parameter	Symbol	Conditions	Min	Typ	Max	Units
Static						
Drain-Source Breakdown Voltage	BV_{DSS}	$I_D=250\mu\text{A}$, $V_{GS}=0\text{V}$	30			V
Breakdown Voltage Temp. Coefficient	$\Delta BV_{DSS}/\Delta T_J$	$I_D=1\text{mA}$, Reference to 25°C		22		mV/ $^\circ\text{C}$
Static Drain-to-Source On-Resistance	$R_{DS(ON)}$	$V_{GS}=10\text{V}$, $I_D=15\text{A}$ ③		5.2	6.5	m Ω
		$V_{GS}=4.5\text{V}$, $I_D=12\text{A}$ ③		6.5	8.2	
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$, $I_D=250\mu\text{A}$	1.35	1.8	2.25	V
Gate Threshold Voltage Coefficient	$\Delta V_{GS(th)}/\Delta T_J$			-5.6		mV/ $^\circ\text{C}$
Drain-to-Source Leakage Current	I_{DSS}	$V_{DS}=24\text{V}$, $V_{GS}=0\text{V}$			1	μA
		$V_{DS}=24\text{V}$, $V_{GS}=0\text{V}$, $T_J=125^\circ\text{C}$			150	μA
Gate-to-Source Forward Leakage	I_{GSS}	$V_{GS}=20\text{V}$			100	nA
Gate-to-Source Reverse Leakage		$V_{GS}=-20\text{V}$			-100	nA
Forward Transconductance	g_{FS}	$V_{DS}=15\text{V}$, $I_D=12\text{A}$	51			S
Total Gate Charge	Q_g	$V_{DS}=15\text{V}$, $V_{GS}=4.5\text{V}$ $I_D=12\text{A}$, See Fig. 16		17	26	nC
Pre-V _{th} Gate-to-Source Charge	Q_{gs1}			4.7		nC
Post-V _{th} Gate-to-Source Charge	Q_{gs2}			1.6		nC
Gate-to-Drain Charge	Q_{gd}			5.7		nC
Gate Charge Overdrive	Q_{gdor}			5		nC
Switch Charge ($Q_{gs2} + Q_{gd}$)	Q_{sw}			7.3		nC
Output Charge	Q_{oss}	$V_{DS}=16\text{V}$, $V_{GS}=0\text{V}$		10		nC
Turn-On Delay Time	$t_{D(on)}$	$V_{DD}=16\text{V}$, $V_{GS}=4.5\text{V}$ ③ $I_D=12\text{A}$ Clamped Inductive Load		12		ns
Rise Time	t_r			12		ns
Turn-Off Delay Time	$t_{D(off)}$			15		ns
Fall Time	t_f			3.9		ns
Input Capacitance	C_{iss}	$V_{GS}=0\text{V}$, $V_{DS}=15\text{V}$ $f = 1.0\text{MHz}$		2330		pF
Output Capacitance	C_{oss}			460		pF
Reverse Transfer Capacitance	C_{rss}			230		pF



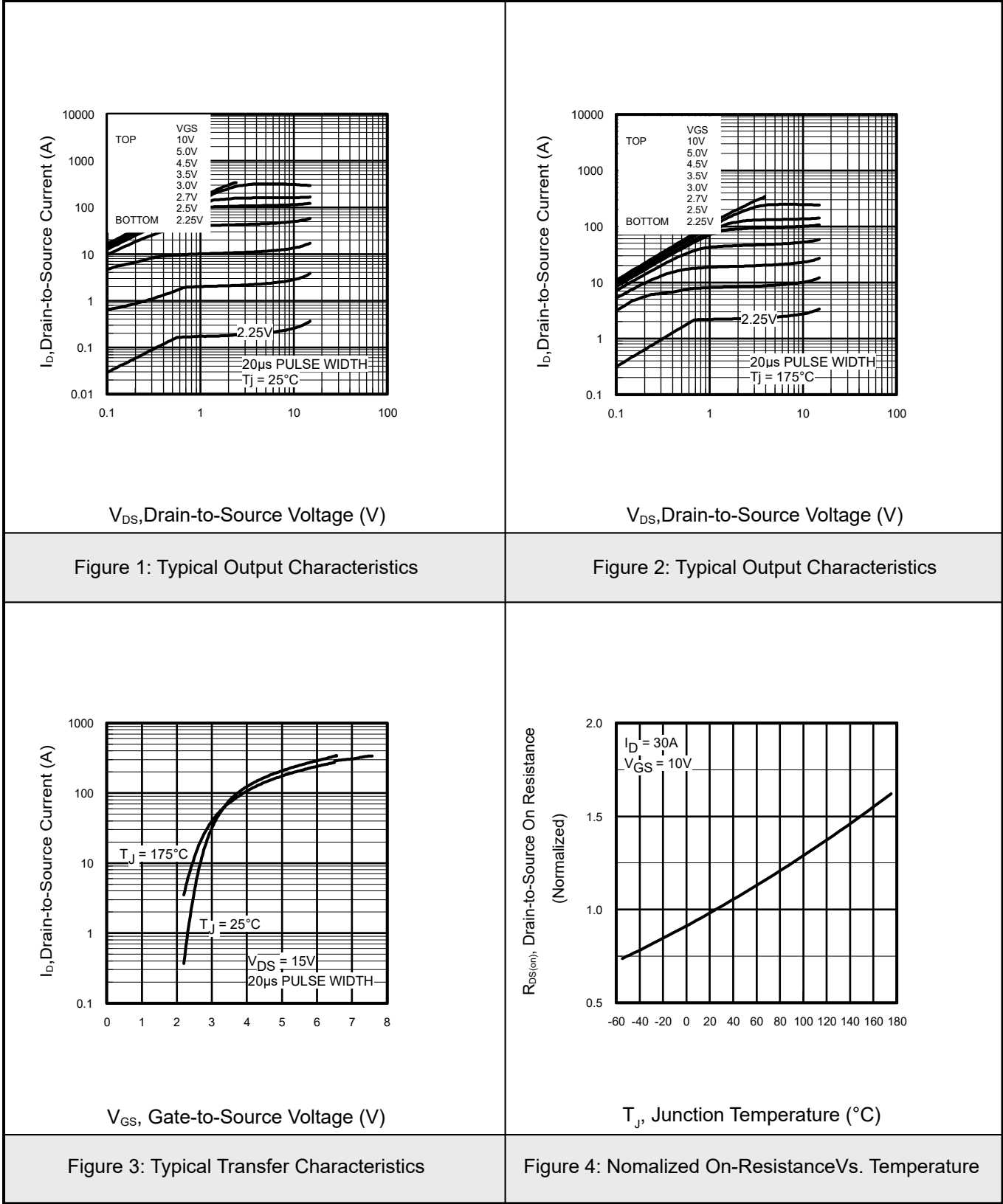
Avalanche Characteristics						
Single Pulse Avalanche Energy ②	E_{AS}				100	mJ
Avalanche Current ①	I_{AR}				12	A
Repetitive Avalanche Energy ①	E_{AR}				7.9	mJ
Diode Characteristics						
Continuous Source Current (Body Diode)	I_S	MOSFET symbol showing the integral reverse p-n junction diode.			86 ④	A
Pulsed Source Current (Body Diode) ①	I_{SM}				340	
Diode Forward Voltage	V_{SD}	$T_J=25^{\circ}\text{C}, I_S=12\text{A}, V_{GS}=0\text{V}$ ③			1	V
Reverse Recovery Time	t_{rr}	$T_J=25^{\circ}\text{C}, I_F=12\text{A}, V_{DS}=15\text{V}$		29	44	ns
Reverse Recovery Charge	Q_{rr}	$di/dt=100\text{A}/\mu\text{s}$ ③		25	37	nC
Forward Turn-On Time	t_{on}	Intrinsic turn-on time is negligible (turn-on is dominated by L_S+L_D)				

Notes:

- ① Repetitive rating; pulse width limited by max. junction temperature.
- ② Starting $T=25^{\circ}\text{C}$, $L=1.4\text{mH}$, $R_G=25\Omega$, $I_{AS}=12\text{A}$.
- ③ Pulse width $\leq 400\mu\text{s}$; duty cycle $\leq 2\%$.
- ④ Calculated continuous current based on maximum allowable junction temperature. Package limitation current is 30A.
- ⑤ When mounted on 1" square PCB (FR-4 or G-10 Material) For recommended footprint and soldering techniques refer to.

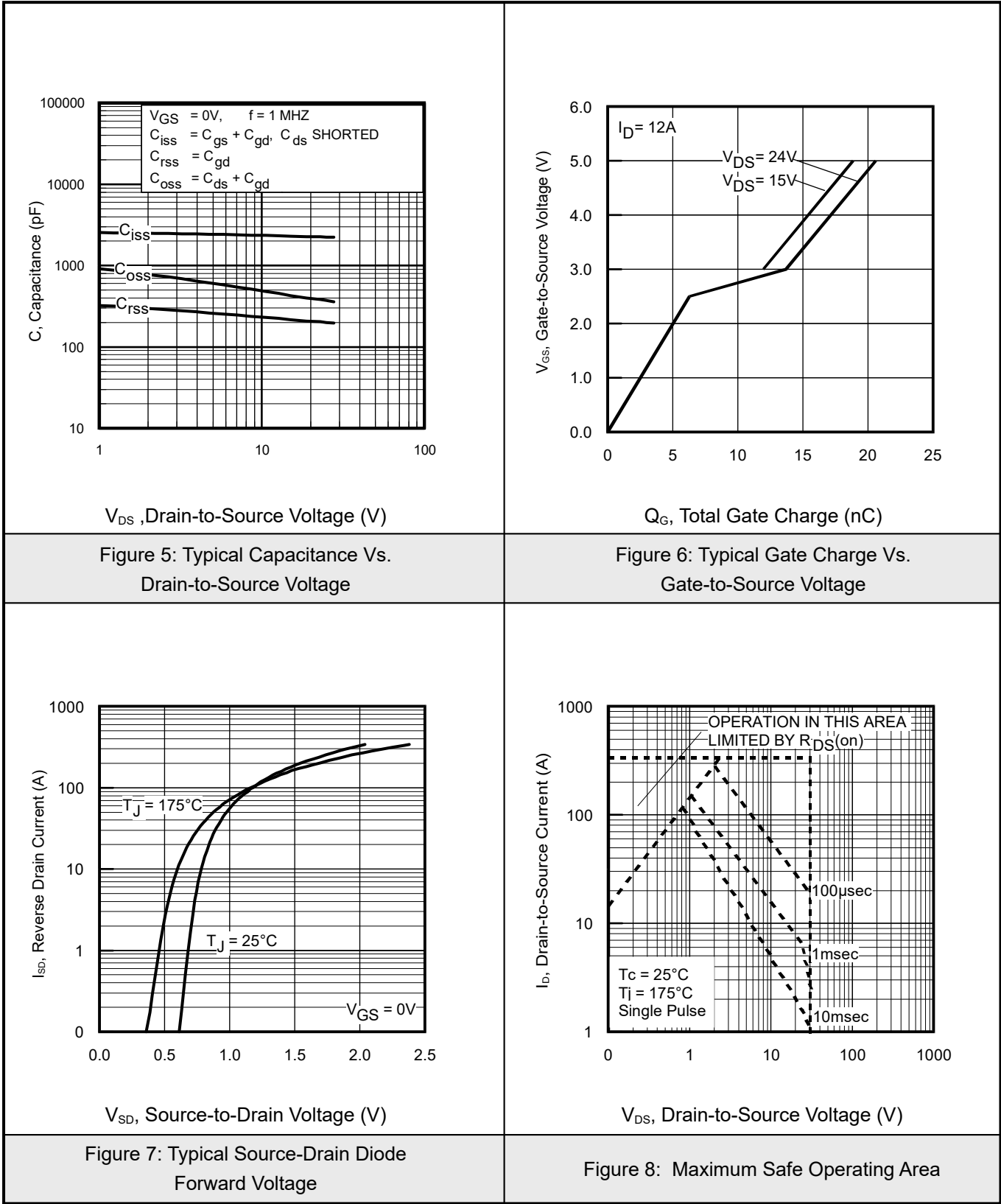


8.1 Typical Characteristics





8.2Typical Characteristics





8.3Typical Characteristics

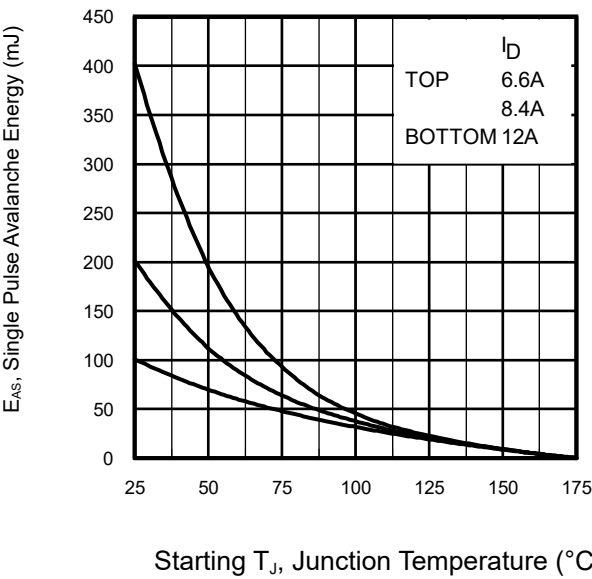


Figure 9: Maximum Avalanche Energy Vs. Drain Current

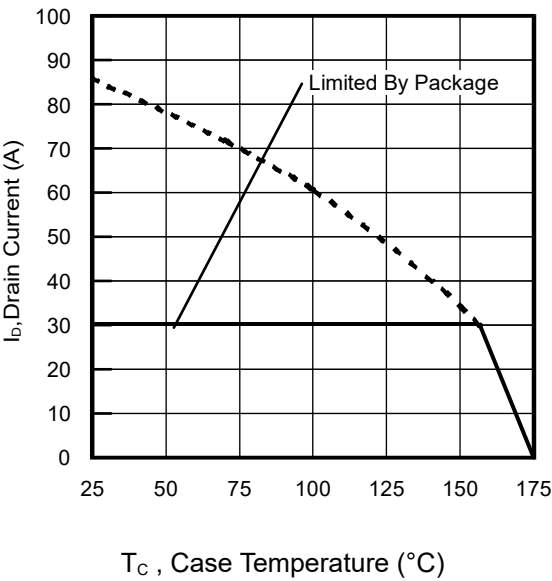


Figure 10: Maximum Drain Current vs. Case Temperature

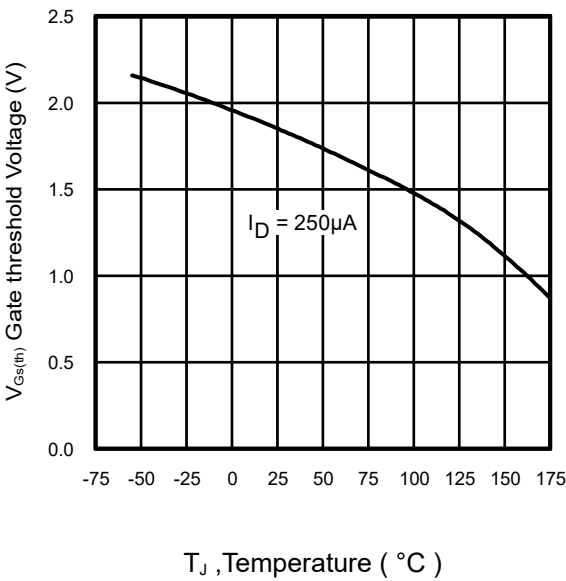


Figure 11: Threshold Voltage vs. Temperature



8.4Typical Characteristics

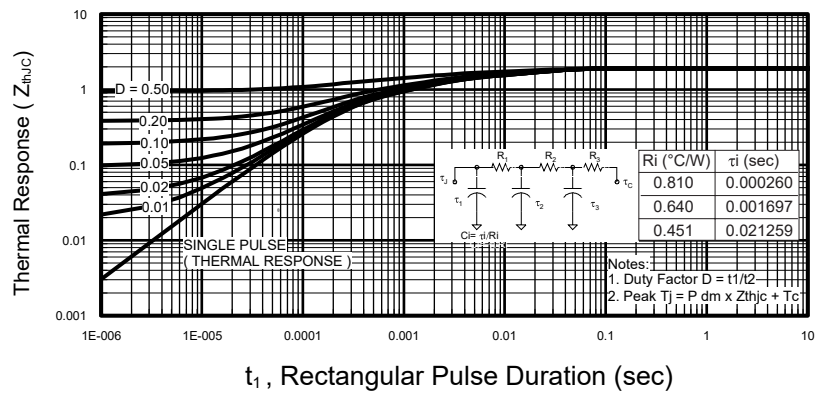


Figure 12: Maximum Effective Transient Thermal Impedance, Junction-to-Case



8.5 Typical Characteristics

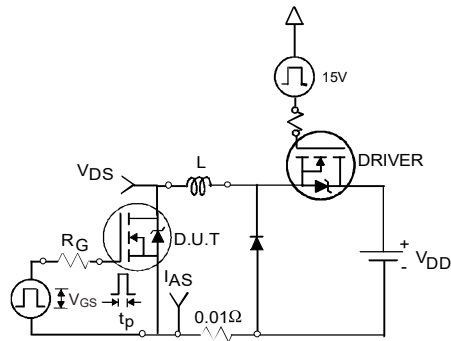


Figure 13a: Unclamped Inductive Test Circuit

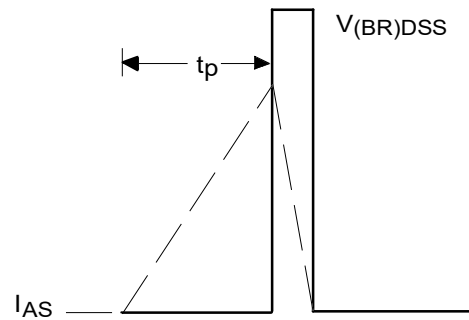


Figure 13b: Unclamped Inductive Waveforms

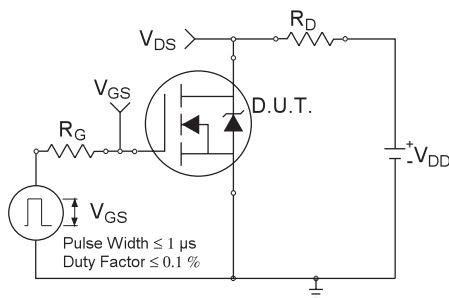


Figure 14a: Switching Time Test Circuit

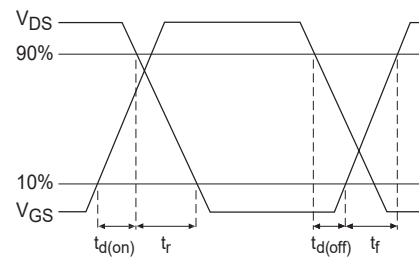


Figure 14b: Switching Time Waveforms

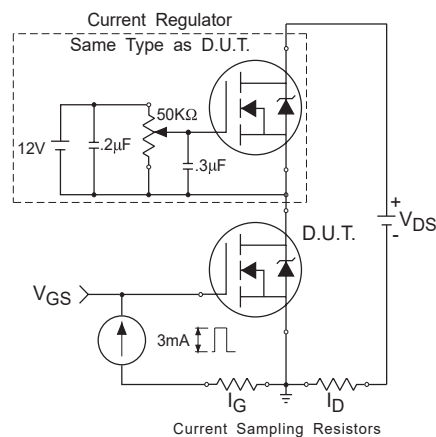
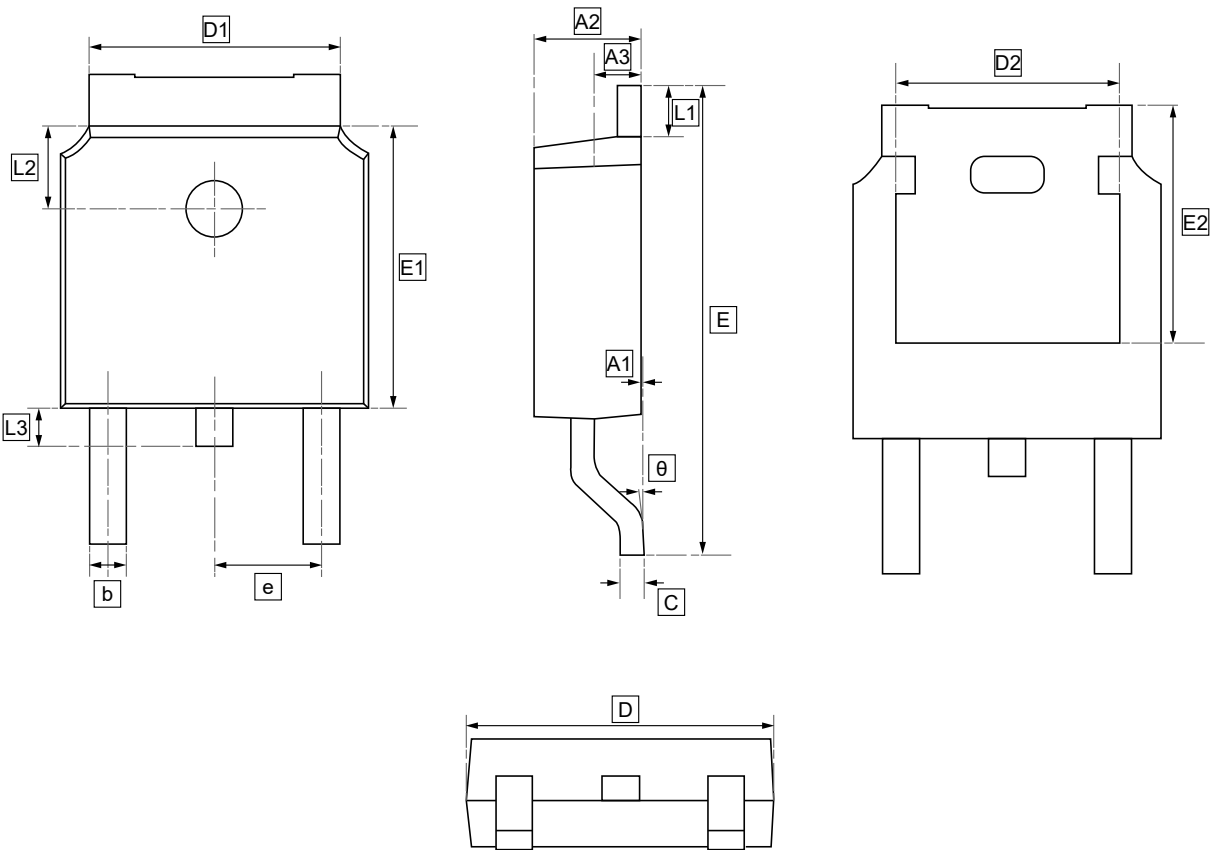


Figure 15: Gate Charge Test Circuit



9.TO-252 Package Outline Dimensions

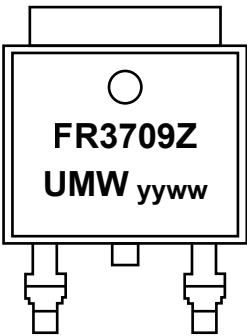


DIMENSIONS (mm are the original dimensions)

Symbol	A1	A2	A3	b	c	D	D1	D2	E	E1	E2	e	L1	L2	L3	θ
Min	0.00	2.18	0.90	0.65	0.46	6.35	4.95	4.32	9.40	5.97	5.21	2.286 BSC	0.89	1.70	0.60	0.00
Max	0.13	2.39	1.10	0.85	0.61	6.73	5.46	4.90	10.41	6.22	5.38		1.27	1.90	1.00	8.00



10.Ordering information



yy: Year Code
ww: Week Code

Order Code	Package	Base QTY	Delivery Mode
UMW IRFR3709ZTR	TO-252	2500	Tape and reel



11.Disclaimer

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